

## Bias Resistor Transistor

### NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

- Applications

Inverter, Interface, Driver

- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
  - 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
  - 3) Only the on/off conditions need to be set for operation, making the device design easy.
- We declare that the material of product compliance with RoHS requirements.
  - S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

● **Absolute maximum ratings (Ta=25°C)**

Parameter	Symbol	Limits		Unit
Supply voltage	Vcc	50		V
Input voltage	V <sub>IN</sub>	-10 to +30		V
Output current	I <sub>c</sub>	500		mA
Power dissipation	P <sub>D</sub>	200		mW
Junction temperature	T <sub>j</sub>	150		°C
Storage temperature	T <sub>stg</sub>	-55 to +150		°C

#### DEVICE MARKING AND RESISTOR VALUES

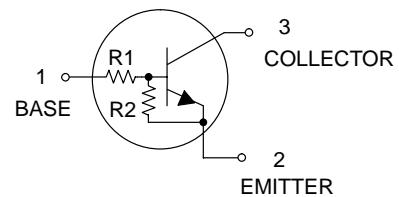
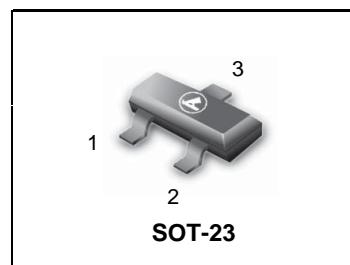
Device	Marking	R1 (K)	R2 (K)	Shipping
LDTD143ELT1G S-LDTD143ELT1G	E6	4.7	4.7	3000/Tape & Reel
LDTD143ELT3G S-LDTD143ELT3G	E6	4.7	4.7	10000/Tape & Reel

● **Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V <sub>I</sub> (off)	—	—	0.5	V	V <sub>cc</sub> =5V, I <sub>o</sub> =100μA
	V <sub>I</sub> (on)	3	—	—		V <sub>o</sub> =0.3V, I <sub>o</sub> =20mA
Output voltage	V <sub>O</sub> (on)	—	0.1	0.3	V	I <sub>o</sub> / I <sub>e</sub> =50mA / 2.5mA
Input current	I <sub>i</sub>	—	—	1.8	mA	V <sub>i</sub> =5V
Output current	I <sub>o</sub> (off)	—	—	0.5	μA	V <sub>cc</sub> =50V, V <sub>i</sub> =0V
DC current gain	G <sub>i</sub>	47	—	—	—	V <sub>o</sub> =5V, I <sub>o</sub> =50mA
Input resistance	R <sub>i</sub>	3.29	4.7	6.11	kΩ	—
Resistance ratio	R <sub>2</sub> / R <sub>1</sub>	0.8	1	1.2	—	—
Transition frequency	f <sub>T</sub> *	—	200	—	MHz	V <sub>ce</sub> =10V, I <sub>e</sub> = -50mA, f=100MHz

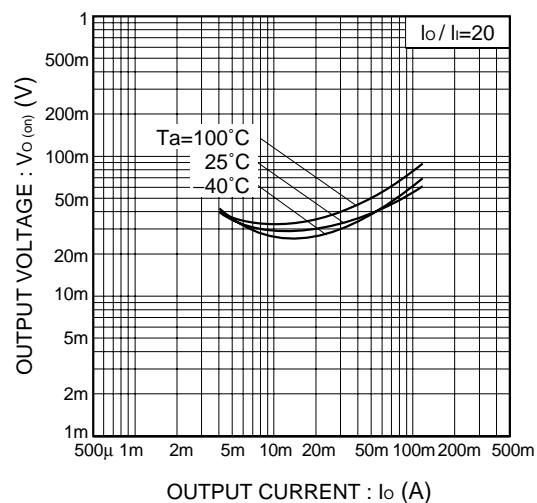
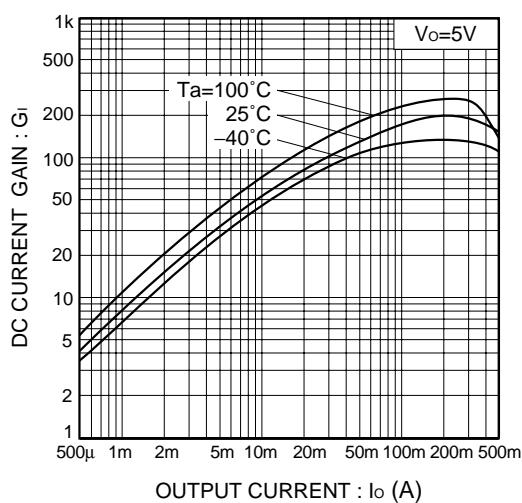
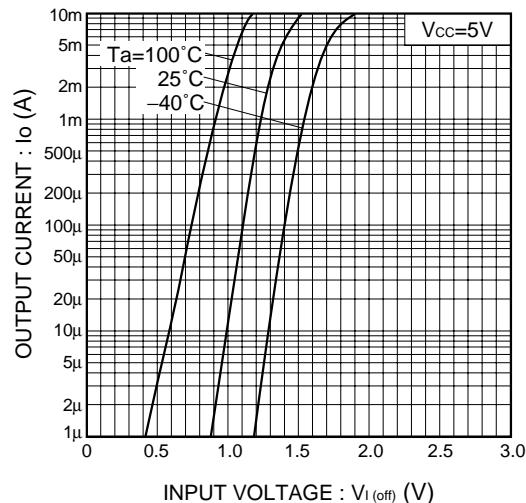
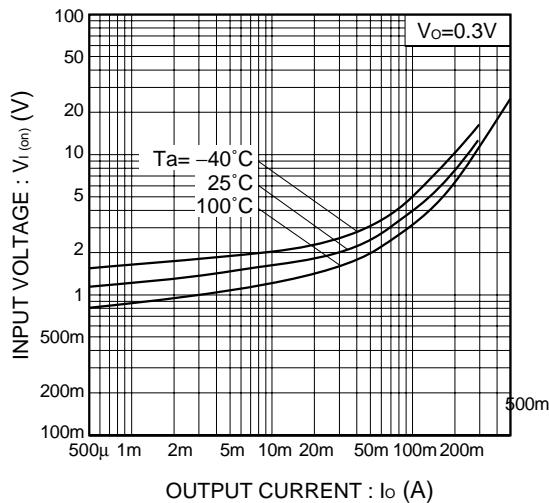
\* Characteristics of built-in transistor

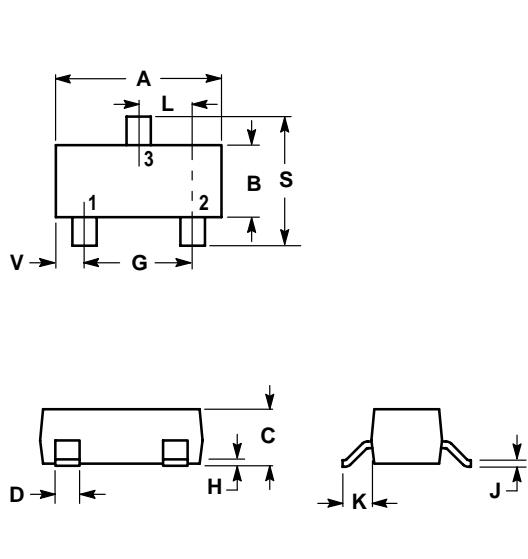
**LDTD143ELT1G  
S-LDTD143ELT1G**



## **LDTD143ELT1G;S-LDTD143ELT1G**

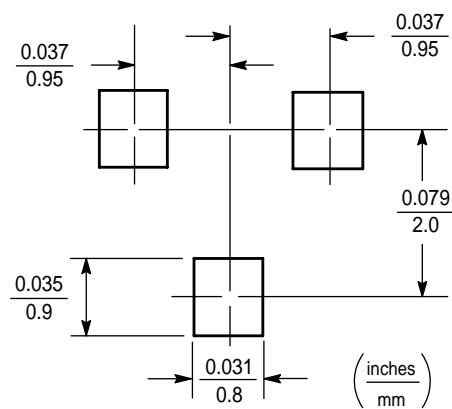
### ●Electrical characteristic curves



**LDTD143ELT1G;S-LDTD143ELT1G**
**SOT-23**

**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60



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